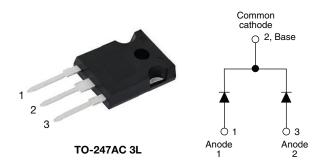
Vishay Semiconductors



Hyperfast Rectifier, 2 x 30 A FRED Pt®



PRIMARY CHARACTERISTICS									
I _{F(AV)}	2 x 30 A								
V _R	300 V								
V _F at I _F	0.92 V								
t _{rr} typ.	See Recovery table								
T _J max.	175 °C								
Package	TO-247AC 3L								
Circuit configuration	Common cathode								

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC[®]-JESD 47



HALOGEN

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

300 V series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS						
Repetitive peak reverse voltage	V _{RRM}		300	V						
per leg		T _C = 143 °C	30							
Average rectified forward current total device	IF(AV)	1C = 143 C	60	А						
Non-repetitive peak surge current per leg	I _{FSM}	T _J = 25 °C, t _p = 10 ms	300							
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C						

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R			-	-					
Forward voltage	V _F	I _F = 30 A	-	1.08	1.25	V				
	٧F	I _F = 30 A, T _J = 125 °C	-	0.92	1.00					
Poverse leakage aurrent		$V_{R} = V_{R}$ rated	-	0.05	60					
Reverse leakage current	I _R	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	20	300 µA					
Junction capacitance	CT	C _T V _R = 300 V		70	-	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nH				

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST C	ONDITIONS	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 1.0 \text{ A}$	50 A/µs, V _R = 30 V	-	-	55				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	39	-	ns			
		T _J = 125 °C		-	57	-				
Deals recovery ourrent		T _J = 25 °C	$I_{\rm F} = 30 {\rm A}$	-	2.8	-	Α			
Peak recovery current	I _{RRM}	T _J = 125 °C	dl _F /dt = - 200 A/µs V _R = 200 V	-	7.5	-	~			
Reverse recovery charge	0	T _J = 25 °C		-	55	-	nC			
	Q _{rr}	T _J = 125 °C		-	214	-	nC			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS					
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C				
Thermal resistance, junction to case per leg	R _{thJC}		-	0.5	0.9					
Thermal resistance, junction to ambient per leg	R _{thJA}	R _{thJA} Typical socket mount		-	40	°C/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.4	-					
Weight			-	6.0	-	g				
Weight			-	0.22	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)				
Marking device		Case style TO-247AC 3L	60CPH03							



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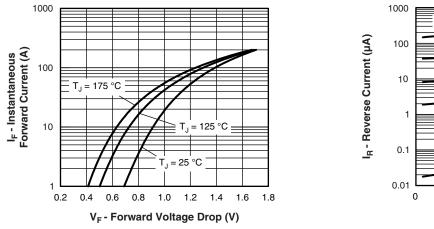


Fig. 1 - Typical Forward Voltage Drop Characteristics

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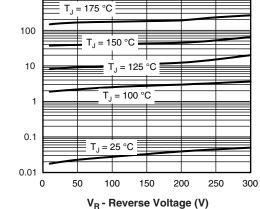


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

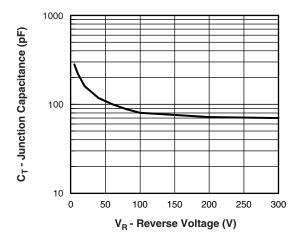
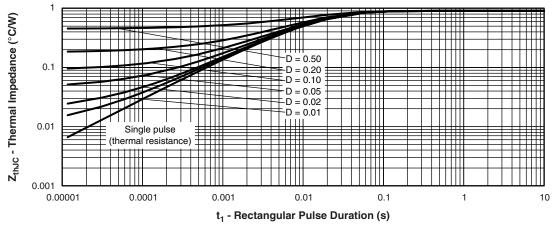


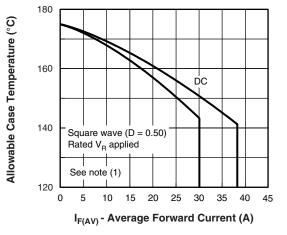
Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



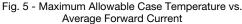


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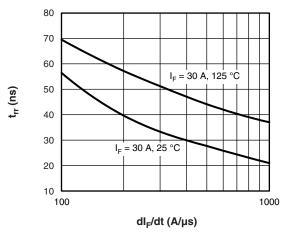


Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = rated V_R

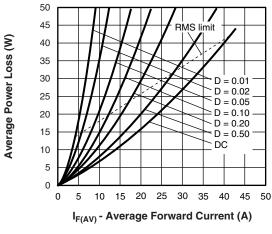


Fig. 7 - Forward Power Loss Characteristics

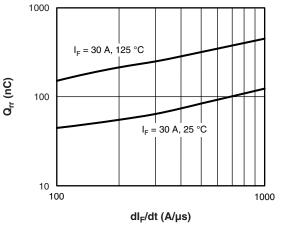


Fig. 8 - Typical Stored Charge vs. dl_F/dt

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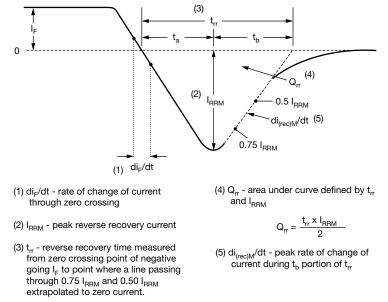


Fig. 9 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Davias and-		CO	•	D		00	
Device code	VS-	60	С	Р	Н	03	-N3
			(3)		(5)	(6)	
	(1)	(2)	3	(4)	9	\bigcirc	(7)
	1	- Vis	hay Ser	nicondu	ctors pro	oduct	
	2	- Cui	rent rati	ng (60 =	= 60 A)		
	3 -	Circ	cuit conf	iguratio	n:		
		C =	commo	on catho	de		
	4 -	- Pao	kage:				
		P =	TO-247	7AC (mc	odified)		
	5 -	• H=	hyperfa	ast recov	/ery		
	6	· Vol	tage co	de (03 =	300 V)		
	7 -	· Env	vironme	ntal digit	:		
		-N3	= halog	gen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-60CPH03-N3	25	500	Antistatic plastic tube						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96138						
Part marking information	www.vishay.com/doc?95007						

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TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTED	STWDOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension Q

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